Diode Semiconductor Device - Page 1 of 1



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In	closure Material:
G	ass
0	verall Length:
45	.0 millimeters
Te	rminal Length:
25	.0 millimeters
0	verall Diameter:
2.	3 millimeters
Jo	int Electronic Device Engineering Council/jedec/case Outline Designation:
D	-35
М	ounting Method:
Te	rminal
Fe	atures Provided:
Н	ermetically sealed case
Se	miconductor Material:
Si	icon
V	Itage Rating In Volts Per Characteristic:
5.) reverse voltage, peak
C	Irrent Rating Per Characteristic:
30	.00 milliamperes source cutoff current preset
Pe	wer Rating Per Characteristic:
15	0.0 milliwatts small-signal input power, common-collector absolute
М	aximum Operating Tempurature Per Measurement Point:
17	5.0 degrees celsius junction
Te	rminal Type And Quantity:
2	uninsulated wire lead
SI	elf Life:
N/	a
U	it Of Measure:
D	militarization:
N	
Fi	g:
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